

Two-dimensional electronic structure for high thermoelectric performance in halide perovskite $\text{Cs}_2\text{Au(I)Au(III)I}_6$

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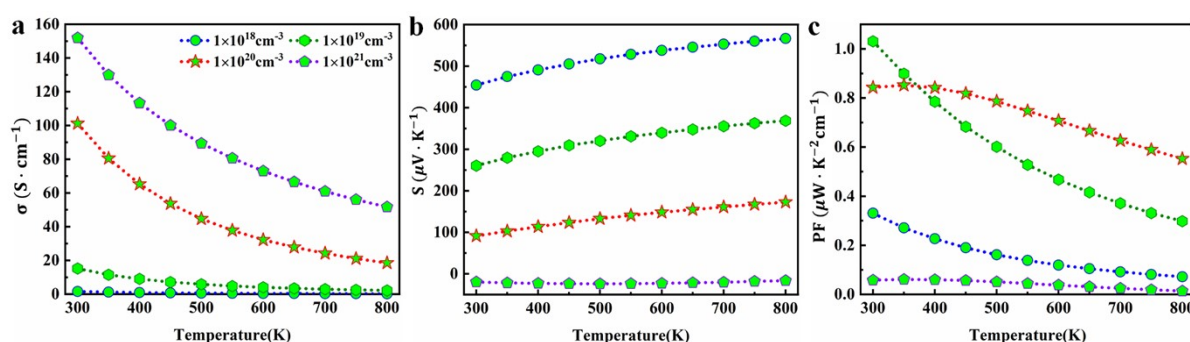


Fig.S1 Out-of-plane electrical transport coefficients for *p*-type $\text{Cs}_2\text{Au(I)Au(III)I}_6$ as functions of temperature and hole concentration, (a) electrical conductivity, (b) Seebeck coefficient and (c) power factor.

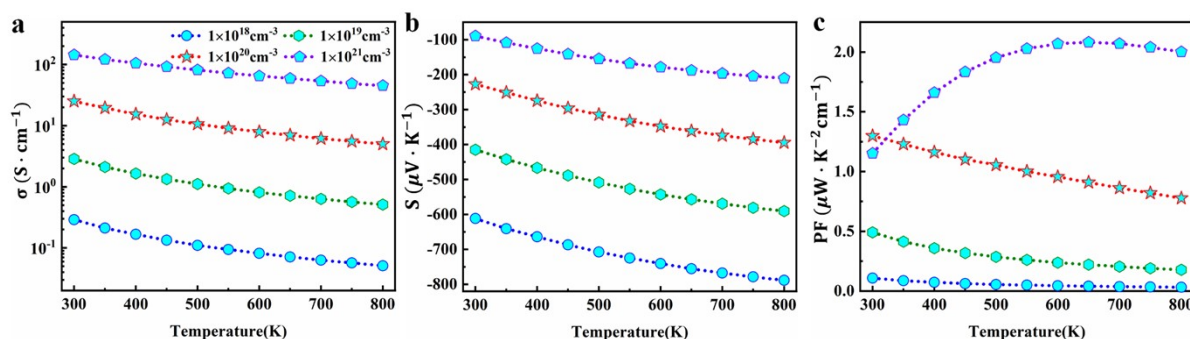


Fig.S2 Out-of-plane electrical transport coefficients for *n*-type $\text{Cs}_2\text{Au(I)Au(III)I}_6$ as functions of temperature and electron concentration, (a) electrical conductivity, (b) Seebeck coefficient and (c) power factor.

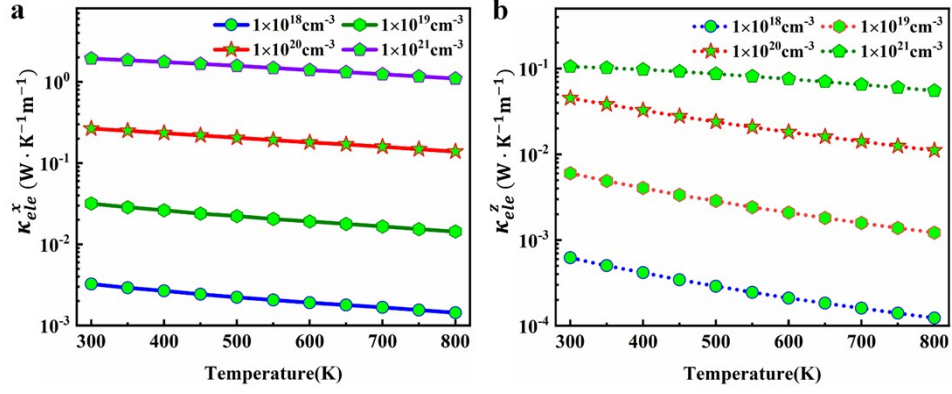


Fig.S3 (a) In-plane and (b) out-of-plane electrical thermal conductivity as functions of temperature and carrier concentration for *p*-type $\text{Cs}_2\text{Au(I)Au(III)I}_6$.

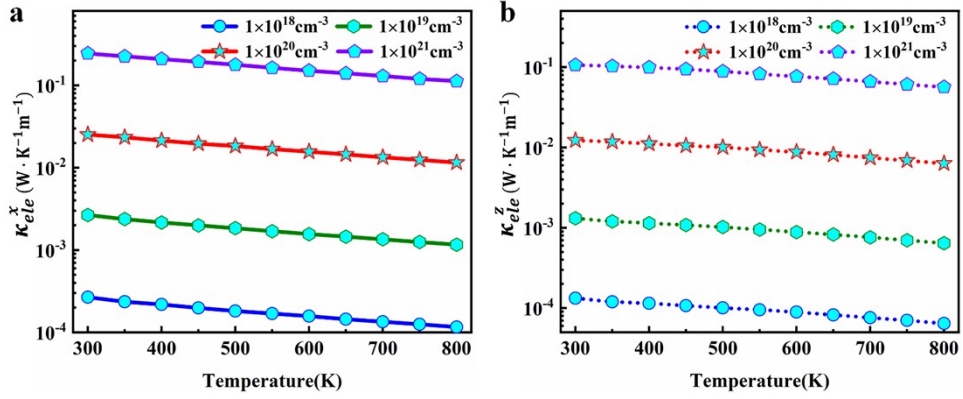


Fig.S4 (a) In-plane and (b) out-of-plane electrical thermal conductivity as functions of temperature and carrier concentration for *n*-type $\text{Cs}_2\text{Au(I)Au(III)I}_6$.

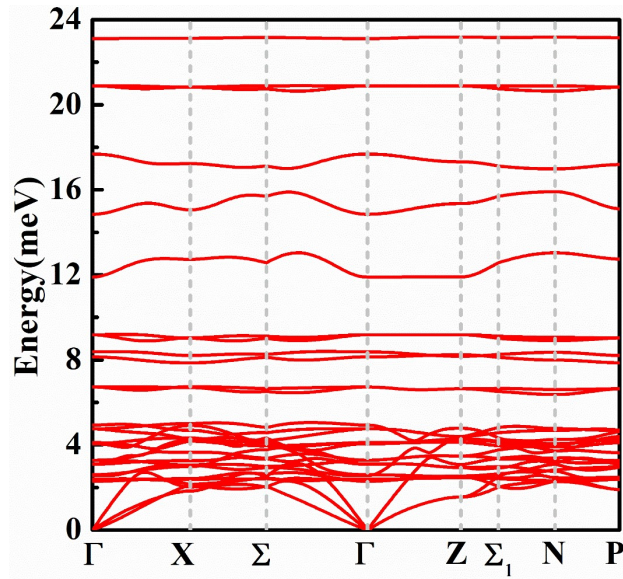


Fig.S5 Phonon dispersion of $\text{Cs}_2\text{Au(I)Au(III)I}_6$.